# 2 Channel Headset Speaker EMI Filter with ESD Protection

### **Features**

- Two channels of EMI filtering
- Pi-style EMI filters in a capacitor-resistor-capacitor (C-R-C) network
- Greater than 40dB attenuation at 1GHz
- ±8kV ESD protection on each channel
- (IEC 61000-4-2 Level 4, contact discharge)
- ±15kV ESD protection in each channel (HBM)
- Supports AC signals—ideal for audio applications
- Extremely low lead inductance for optimum filter and ESD performance
- 5-bump, 0.950mm X 1.410mm footprint Chip Scale Package (CSP)
- Lead-free version available

### **Applications**

- EMI filtering and ESD protection for headset speaker ports
- Wireless Handsets
- Handheld PCs / PDAs
- MP3 Players
- **Digital Camcorders**
- Notebooks
- Desktop PCs

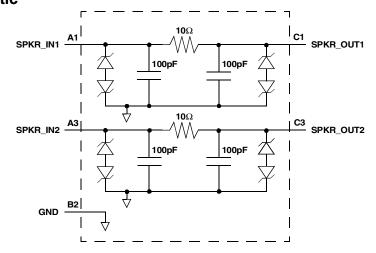
### **Product Description**

The CSPEMI201A is a dual low-pass filter array integrating two pi-style filters (C-R-C) that reduce EMI/RFI emissions while at the same time providing ESD protection. This part is custom-designed to interface with a speaker port on a cellular telephone or similar device. Each high quality filter provides more than 35dB attenuation in the 800-2700 MHz range. These pi-style filters support bidirectional filtering, controlling EMI both to and from a speaker element. They also support bipolar signals with a cutoff frequency of 31MHz, enabling audio signals to pass through without distortion.

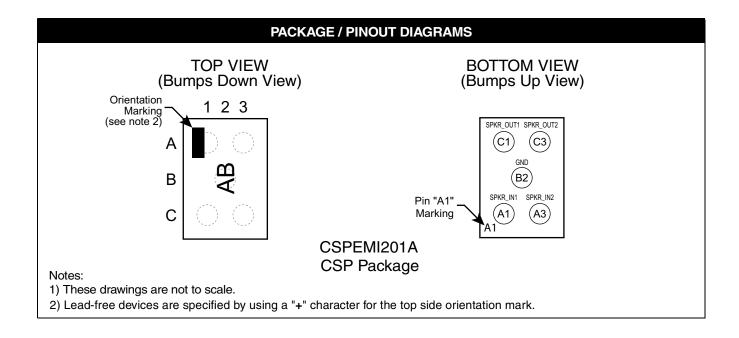
In addition, the CSPEMI201A provides a very high level of protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). The CSPEMI201A can safely dissipate ESD strikes of 8kV, the maximum requirement of the IEC 61000-4-2 international standard. Using the MIL-STD-883 (Method 3015) specification for Human Body Model (HBM) ESD, the device provides protection for contact discharges to greater than 15kV.

The CSPEMI201A is particularly well suited for portable electronics (e.g., cellular telephones, PDAs, notebook computers) because of its small package format and low weight. The CSPEMI201A is available in a space-saving, low-profile Chip Scale Package with optional lead-free finishing.

### **Electrical Schematic**



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PIN DESCRIPTIONS					
PIN	NAME	DESCRIPTION			
A1	SPKR_IN1	Speaker Input 1 (from audio circuitry)			
А3	SPKR_IN2	Speaker Input 2 (from audio circuitry)			
B2	GND	Device Ground			
C1	SPKR_OUT1	Speaker Output 1 (to speaker)			
C3	SPKR_OUT2	Speaker Output 2 (to speaker)			

# **Ordering Information**

PART NUMBERING INFORMATION								
		Standa	rd Finish	Lead-fre	e Finish <sup>2</sup>			
		Ordering Part		Ordering Part				
Pins	Package	Number <sup>1</sup>	Part Marking	Number <sup>1</sup>	Part Marking			
5	CSP	CSPEMI201A	AB	CSPEMI201AG	AB			

Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.

Note 2: Lead-free devices are specified by using a "+" character for the top side orientation mark.

# **Specifications**

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	RATING	UNITS				
Storage Temperature Range	-65 to +150	°C				
DC Power per Resistor	100	mW				
DC Package Power Rating	200	mW				

STANDARD OPERATING CONDITIONS						
PARAMETER	RATING	UNITS				
Operating Temperature Range	-40 to +85	°C				

	ELECTRICAL OPERATING CHARACTERISTICS <sup>1</sup>							
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS		
R	Resistance		9	10	11	Ω		
С	Capacitance		80	100	120	pF		
I <sub>LEAK</sub>	Diode Leakage Current	V <sub>IN</sub> =5.0V			1.0	μΑ		
V <sub>SIG</sub>	Signal Voltage Positive Clamp Negative Clamp	I <sub>LOAD</sub> = 10mA	5 -5	7 -10	15 -15	< < < < < < < < < < < < < < < < < < <		
V <sub>ESD</sub>	In-system ESD Withstand Voltage a) Human Body Model, MIL-STD-883, Method 3015 b) Contact Discharge per IEC 61000-4-2 Level 4	Notes 2,4 and 5	±15 ±8			kV kV		
V <sub>CL</sub>	Clamping Voltage during ESD Discharge MIL-STD-883 (Method 3015), 8kV Positive Transients Negative Transients	Notes 2,3,4 and 5		+15 -19		V V		
f <sub>C</sub>	Cut-off frequency $Z_{SOURCE} = 50\Omega$ , $Z_{LOAD} = 50\Omega$	R = 10Ω, C = 100pF		31		MHz		

Note 1: T<sub>A</sub>=25°C unless otherwise specified.

Note 2: ESD applied to input and output pins with respect to GND, one at a time.

Note 3: Clamping voltage is measured at the opposite side of the EMI filter to the ESD pin. For example, if ESD is applied to Pin A1, then clamping voltage is measured at Pin C1.

Note 4: Unused pins are left open

Note 5: These parameters are guaranteed by design and characterization.

### **Performance Information**

Typical Filter Performance (nominal conditions unless specified otherwise, 50 Ohm Environment)

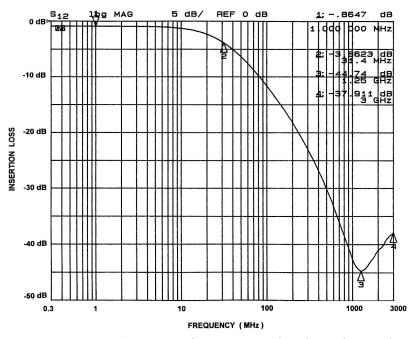


Figure 1. Insertion Loss VS. Frequency (A1-C1 to GND B2)

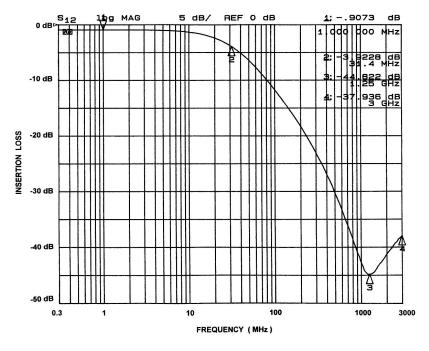


Figure 2. Insertion Loss VS. Frequency (A3-C3 to GND B2)

# **Application Information**

Refer to Application Note AP-217, "The Chip Scale Package", for a detailed description of Chip Scale Packages offered by California Micro Devices.

PRINTED CIRCUIT BOARD RECOMMENDATIONS						
PARAMETER	VALUE					
Pad Size on PCB	0.275mm					
Pad Shape	Round					
Pad Definition	Non-Solder Mask defined pads					
Solder Mask Opening	0.325mm Round					
Solder Stencil Thickness	0.125 - 0.150mm					
Solder Stencil Aperture Opening (laser cut, 5% tapered walls)	0.330mm Round					
Solder Flux Ratio	50/50 by volume					
Solder Paste Type	No Clean					
Pad Protective Finish	OSP (Entek Cu Plus 106A)					
Tolerance — Edge To Corner Ball	±50μm					
Solder Ball Side Coplanarity	<u>+</u> 20μm					
Maximum Dwell Time Above Liquidous	60 seconds					
Soldering Maximum Temperature	260°C					

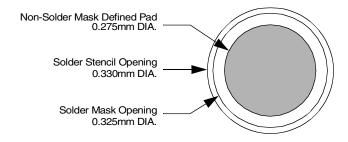


Figure 3. Recommended Non-Solder Mask Defined Pad Illustration

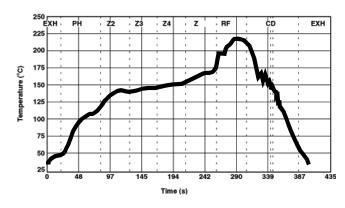


Figure 4. Eutectic (SnPb) Solder **Ball Reflow Profile** 

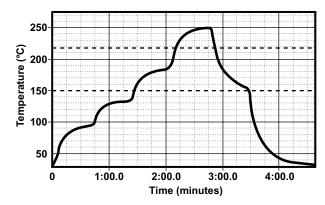


Figure 5. Lead-free (SnAgCu) Solder **Ball Reflow Profile** 

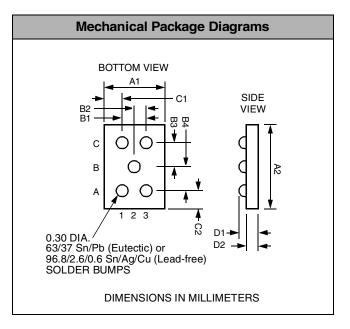
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### **Mechanical Details**

#### **CSP Mechanical Specifications**

CSPEMI201A devices are packaged in a custom Chip Scale Package (CSP). Dimensions are presented below. For complete information on CSP packaging, see the California Micro Devices CSP Package Information document.

PACKAGE DIMENSIONS								
Pack	age	Custom CSP						
Bumps		5						
Dim	M	lillimeters						
Dilli	Min	Nom	Max	Min	Nom	Max		
A1	0.905	0.950	0.995	0.0356	0.0374	0.0392		
A2	1.365	1.410	1.455	0.0537	0.0555	0.0573		
B1	0.495	0.500	0.505	0.0195	0.0197	0.0199		
<b>B2</b> 0.245		0.250	0.255	0.0096	0.0098	0.0100		
В3	0.430	0.435 0.440		0.0169	0.0171	0.0173		
B4	0.430	0.435	0.440	0.0169	0.0171	0.0173 0.0108 0.0126		
C1	0.175	0.225	0.275	0.0069	0.0089			
C2	0.220	0.270	0.320	0.0087	0.0106			
D1	0.561	0.605	0.649	0.0221 0.023		0.0255		
D2	0.355	0.380	0.405	0.0140	0.0150	0.0159		
# per tap		3500 pieces						
Controlling dimension: millimeters								



**Package Dimensions for** CSPEMI201A Chip Scale Package

#### **CSP Tape and Reel Specifications**

PART NUMBER	CHIP SIZE (mm)	POCKET SIZE (mm) B <sub>0</sub> X A <sub>0</sub> X K <sub>0</sub>	TAPE WIDTH W	REEL DIAMETER	QTY PER REEL	P <sub>0</sub>	P <sub>1</sub>
CSPEMI201A	1.41 X 0.95 X 0.6	1.52 X 1.07 X 0.72	8mm	178mm (7")	3500	4mm	4mm

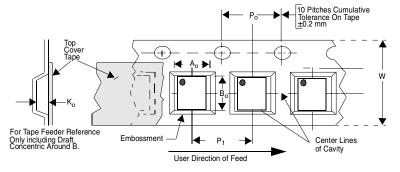


Figure 6. Tape and Reel Mechanical Data

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